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FGB7N60UNDF

600 V, 7 A

Short Circuit Rated IGBT

Features

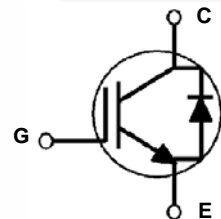
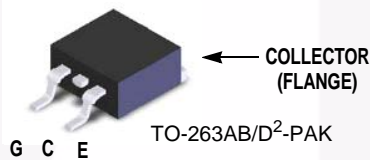
- Short Circuit Rated 10 us
- High Current Capability
- High Input Impedance
- Fast Switching
- RoHS Compliant

Applications

- Sewing Machine, CNC, Home Appliances, Motor Control

General Description

Using advanced NPT IGBT technology, Fairchild's the NPT IGBTs offer the optimum performance for low-power inverter-driven applications where low-losses and short-circuit ruggedness features are essential, such as sewing machine, CNC, motor control and home appliances.



Absolute Maximum Ratings

| Symbol | Description | Ratings | Unit |
|-------------|---|-------------|------------------|
| V_{CES} | Collector to Emitter Voltage | 600 | V |
| V_{GES} | Gate to Emitter Voltage | ± 20 | V |
| I_C | Collector Current @ $T_C = 25^\circ\text{C}$ | 14 | A |
| | Collector Current @ $T_C = 100^\circ\text{C}$ | 7 | A |
| $I_{CM(1)}$ | Pulsed Collector Current @ $T_C = 25^\circ\text{C}$ | 21 | A |
| I_F | Diode Forward Current @ $T_C = 25^\circ\text{C}$ | 7 | A |
| | Diode Forward Current @ $T_C = 100^\circ\text{C}$ | 3.5 | A |
| P_D | Maximum Power Dissipation @ $T_C = 25^\circ\text{C}$ | 83 | W |
| | Maximum Power Dissipation @ $T_C = 100^\circ\text{C}$ | 33 | W |
| T_J | Operating Junction Temperature | -55 to +150 | $^\circ\text{C}$ |
| T_{stg} | Storage Temperature Range | -55 to +150 | $^\circ\text{C}$ |
| T_L | Maximum Lead Temp. for soldering Purposes, 1/8" from case for 5 seconds | 300 | $^\circ\text{C}$ |

Notes:

1: Repetitive rating: Pulse width limited by max. junction temperature

Thermal Characteristics

| Symbol | Parameter | Typ. | Max. | Unit |
|-------------------------------|--|------|------|---------------------------|
| $R_{\theta JC}(\text{IGBT})$ | Thermal Resistance, Junction to Case | | 1.5 | $^\circ\text{C}/\text{W}$ |
| $R_{\theta JC}(\text{Diode})$ | Thermal Resistance, Junction to Case | | 3.5 | $^\circ\text{C}/\text{W}$ |
| $R_{\theta JA}$ | Thermal Resistance, Junction to Ambient (PCB Mount)(2) | | 40 | $^\circ\text{C}/\text{W}$ |

Notes:

2: Mounted on 1" square PCB (FR4 or G-10 material)

Package Marking and Ordering Information

| Device Marking | Device | Package | Rel Size | Tape Width | Quantity |
|----------------|-------------|-------------------------------|----------|------------|----------|
| FGB7N60UNDF | FGB7N60UNDF | TO-263AB(D ² -PAK) | | - | 50 |

Electrical Characteristics of the IGBT T_C = 25°C unless otherwise noted

| Symbol | Parameter | Test Conditions | Min. | Typ. | Max. | Unit |
|----------------------------------|---|--|------|------|------|------|
| Off Characteristics | | | | | | |
| BV _{CES} | Collector to Emitter Breakdown Voltage | V _{GE} = 0V, I _C = 250μA | 600 | - | - | V |
| I _{CES} | Collector Cut-Off Current | V _{CE} = V _{CES} , V _{GE} = 0V | - | - | 1 | mA |
| I _{GES} | G-E Leakage Current | V _{GE} = V _{GES} , V _{CE} = 0V | - | - | ±10 | μA |
| On Characteristics | | | | | | |
| V _{GE(th)} | G-E Threshold Voltage | I _C = 7mA, V _{CE} = V _{GE} | 5.5 | 6.8 | 8.5 | V |
| V _{CE(sat)} | Collector to Emitter Saturation Voltage | I _C = 7A, V _{GE} = 15V | - | 1.9 | 2.3 | V |
| | | I _C = 7A, V _{GE} = 15V, T _C = 125°C | - | 2.1 | - | V |
| Dynamic Characteristics | | | | | | |
| C _{ies} | Input Capacitance | V _{CE} = 30V, V _{GE} = 0V, f = 1MHz | - | 275 | | pF |
| C _{oes} | Output Capacitance | | - | 41 | | pF |
| C _{res} | Reverse Transfer Capacitance | | - | 10 | | pF |
| Switching Characteristics | | | | | | |
| t _{d(on)} | Turn-On Delay Time | V _{CC} = 400V, I _C = 7A, R _G = 10Ω, V _{GE} = 15V, Inductive Load, T _C = 25°C | - | 5.9 | | ns |
| t _r | Rise Time | | - | 4.2 | | ns |
| t _{d(off)} | Turn-Off Delay Time | | - | 32.3 | | ns |
| t _f | Fall Time | | - | 68 | 89 | ns |
| E _{on} | Turn-On Switching Loss | | - | 99 | | μJ |
| E _{off} | Turn-Off Switching Loss | | - | 104 | | μJ |
| E _{ts} | Total Switching Loss | - | 203 | | μJ | |
| t _{d(on)} | Turn-On Delay Time | V _{CC} = 400V, I _C = 7A, R _G = 10Ω, V _{GE} = 15V, Inductive Load, T _C = 125°C | - | 6 | | ns |
| t _r | Rise Time | | - | 4.3 | | ns |
| t _{d(off)} | Turn-Off Delay Time | | - | 33.8 | | ns |
| t _f | Fall Time | | - | 113 | | ns |
| E _{on} | Turn-On Switching Loss | | - | 181 | | μJ |
| E _{off} | Turn-Off Switching Loss | | - | 144 | | μJ |
| E _{ts} | Total Switching Loss | - | 325 | | μJ | |
| T _{sc} | Short Circuit Withstand Time | V _{CC} = 350V, R _G = 100Ω, V _{GE} = 15V, T _C = 150°C | 10 | | | us |

Electrical Characteristics of the IGBT $T_C = 25^\circ\text{C}$ unless otherwise noted

| | | | | | | |
|----------|--------------------------|---|---|----|---|----|
| Q_g | Total Gate Charge | $V_{CE} = 400\text{V}, I_C = 7\text{A},$ $V_{GE} = 15\text{V}$ | - | 18 | - | nC |
| Q_{ge} | Gate to Emitter Charge | | - | 3 | - | nC |
| Q_{gc} | Gate to Collector Charge | | - | 13 | - | nC |

Electrical Characteristics of the Diode $T_C = 25^\circ\text{C}$ unless otherwise noted

| Symbol | Parameter | Test Conditions | Min. | Typ. | Max | Unit | |
|----------|-------------------------------|--|---------------------------|------|------|------|----|
| V_{FM} | Diode Forward Voltage | $I_F = 7\text{A}$ | $T_C = 25^\circ\text{C}$ | - | 1.7 | 2.2 | V |
| | | | $T_C = 125^\circ\text{C}$ | - | 1.6 | | |
| t_{rr} | Diode Reverse Recovery Time | $I_F = 7\text{A}, di_F/dt = 200\text{A}/\mu\text{s}$ | $T_C = 25^\circ\text{C}$ | - | 32.3 | | ns |
| | | | $T_C = 125^\circ\text{C}$ | - | 70 | | |
| Q_{rr} | Diode Reverse Recovery Charge | | $T_C = 25^\circ\text{C}$ | - | 59 | | nC |
| | | | $T_C = 125^\circ\text{C}$ | - | 172 | - | |



Typical Performance Characteristics

Figure 1. Typical Output Characteristics

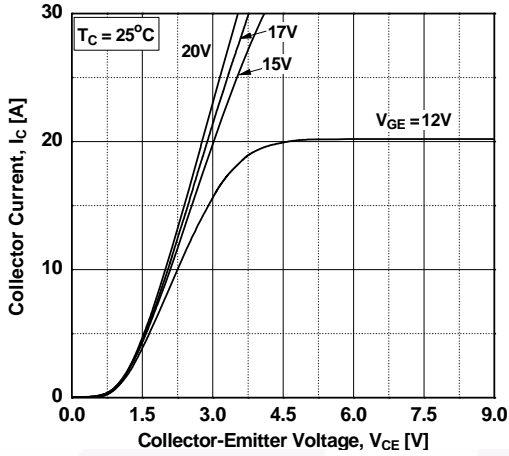


Figure 2. Typical Output Characteristics

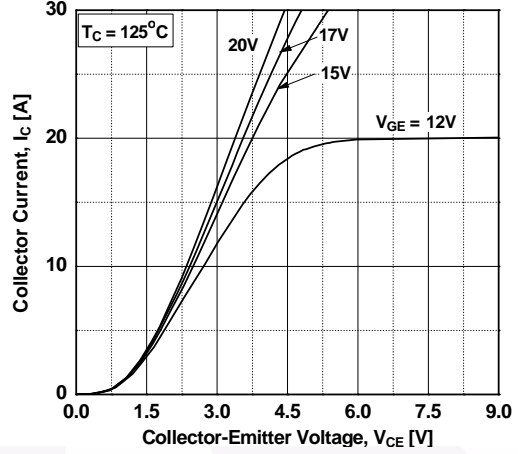


Figure 3. Typical Saturation Voltage Characteristics

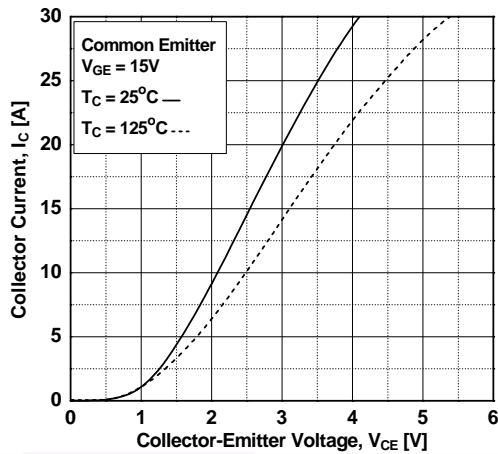


Figure 4. Transfer Characteristics

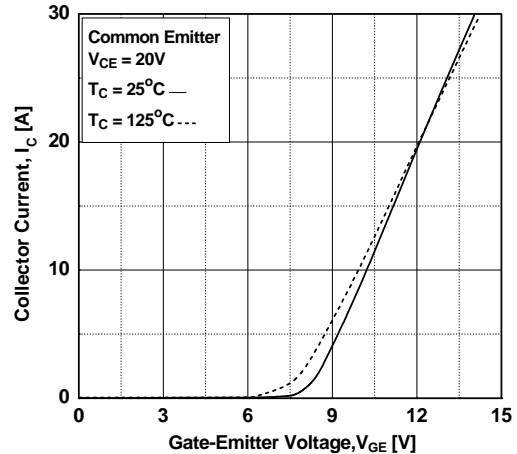


Figure 5. Saturation Voltage vs. Case Temperature at Variant Current Level

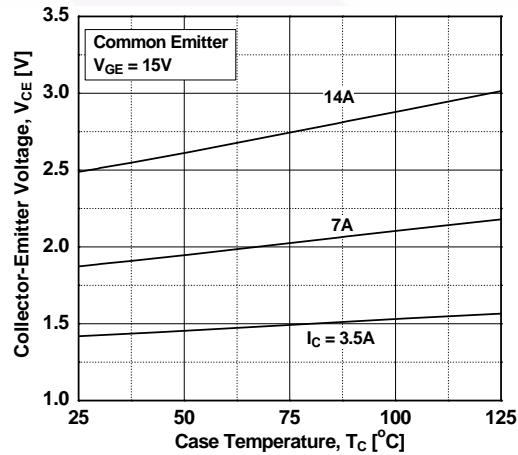
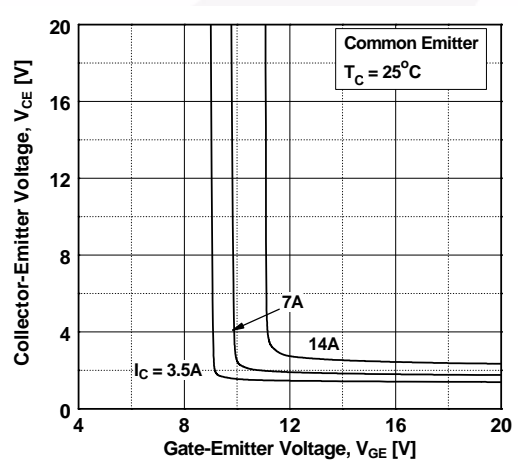


Figure 6. Saturation Voltage vs. Vge



Typical Performance Characteristics

Figure 7. Saturation Voltage vs. V_{GE}

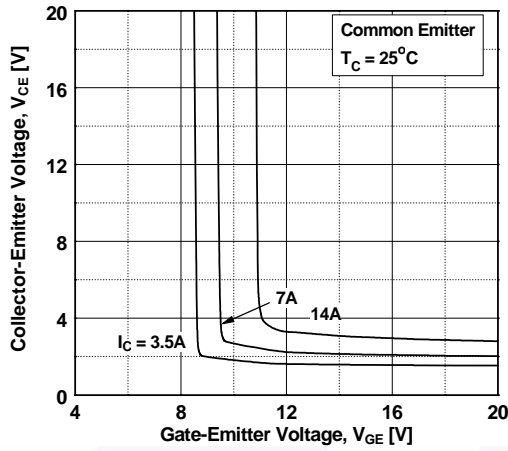


Figure 8. Capacitance Characteristics

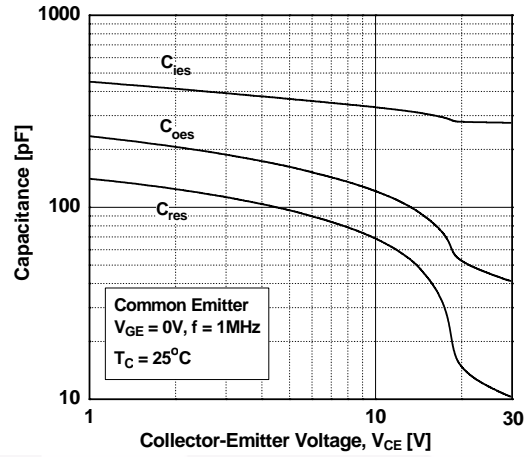


Figure 9. Gate charge Characteristics

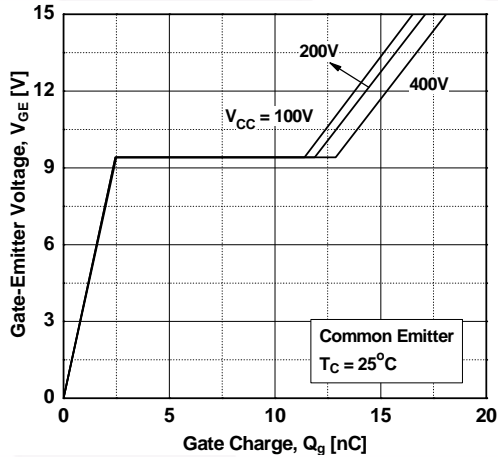


Figure 10. SOA Characteristics

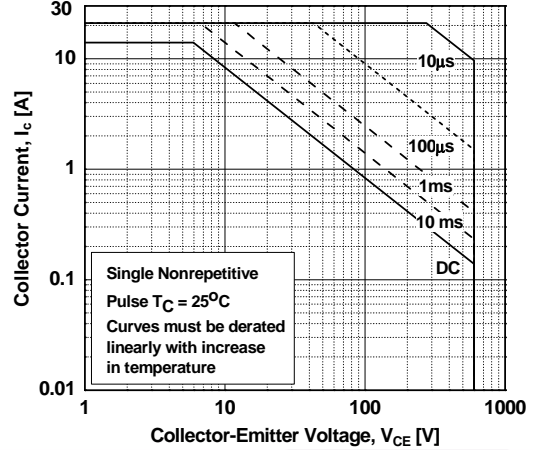


Figure 11. Turn-on Characteristics vs. Gate Resistance

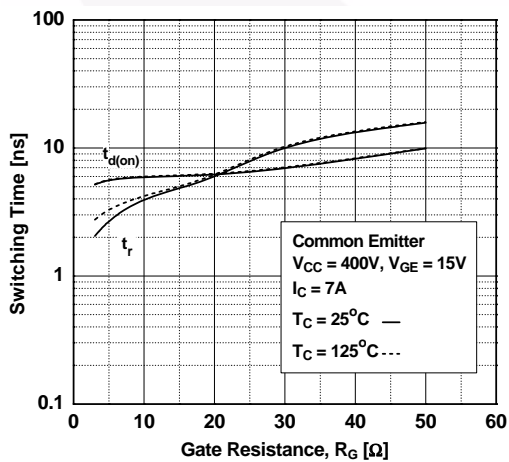
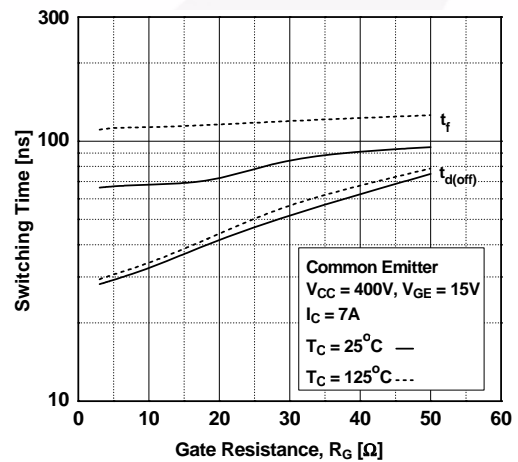


Figure 12. Turn-off Characteristics vs. Gate Resistance



Typical Performance Characteristics

Figure 13. Turn-on Characteristics vs. Collector Current

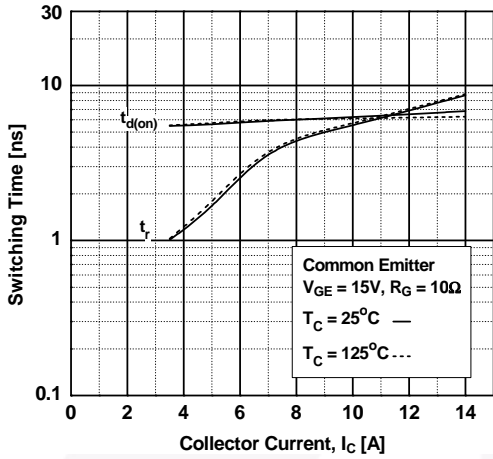


Figure 14. Turn-off Characteristics vs. Collector Current

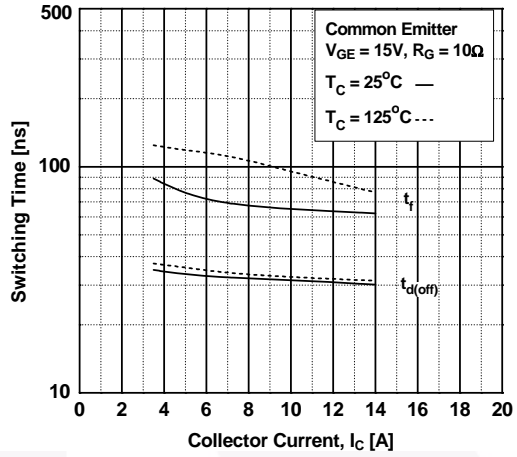


Figure 15. Switching Loss vs. Gate Resistance

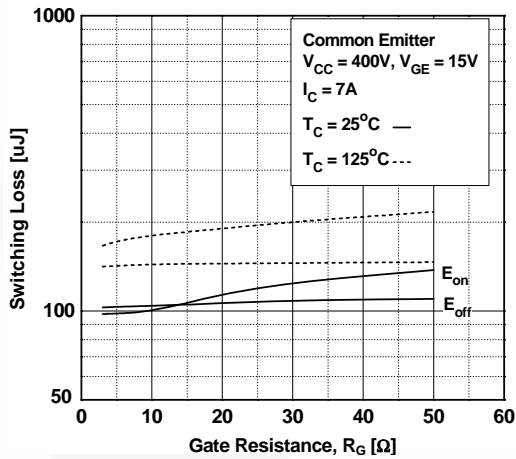


Figure 16. Switching Loss vs Collector Current

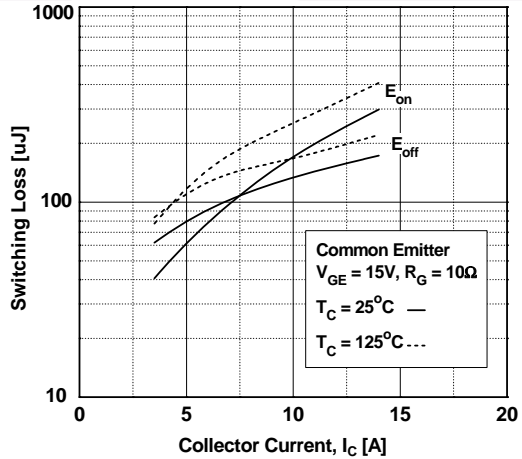


Figure 17. Turn off Switching SOA Characteristics

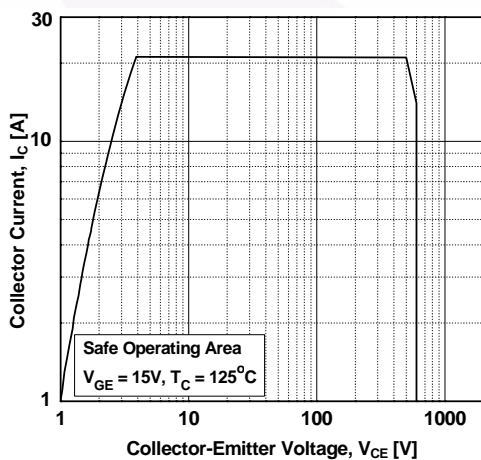
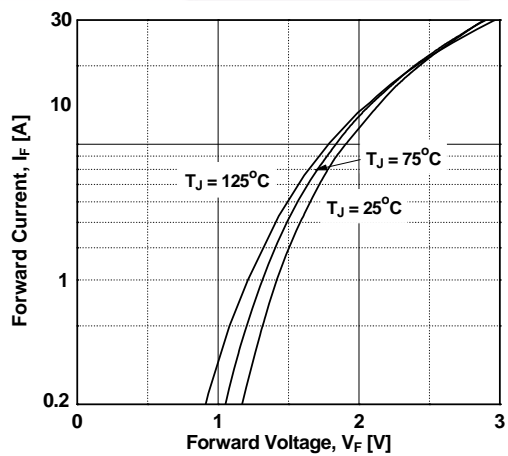


Figure 18. Forward Characteristics



Typical Performance Characteristics

Figure 19. Reverse Current

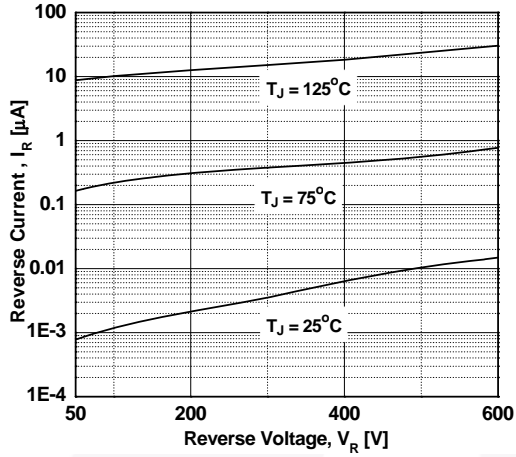


Figure 20. Stored Charge

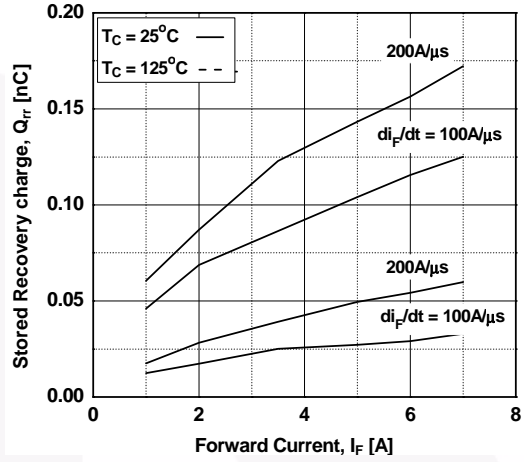


Figure 21. Reverse Recovery Time

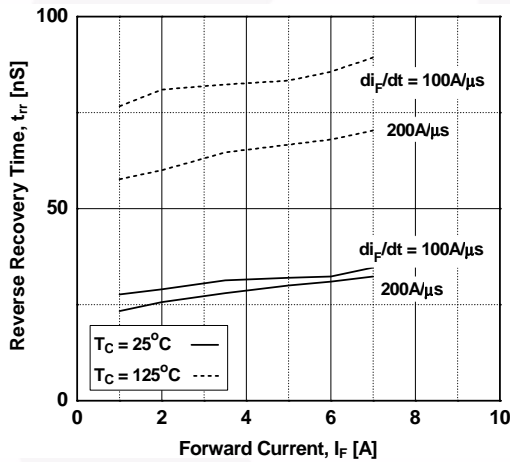
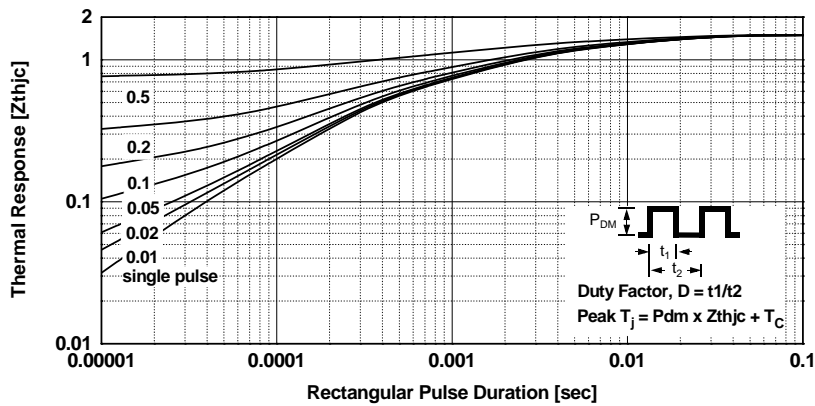


Figure 22. Transient Thermal Impedance of IGBT



Mechanical Dimensions

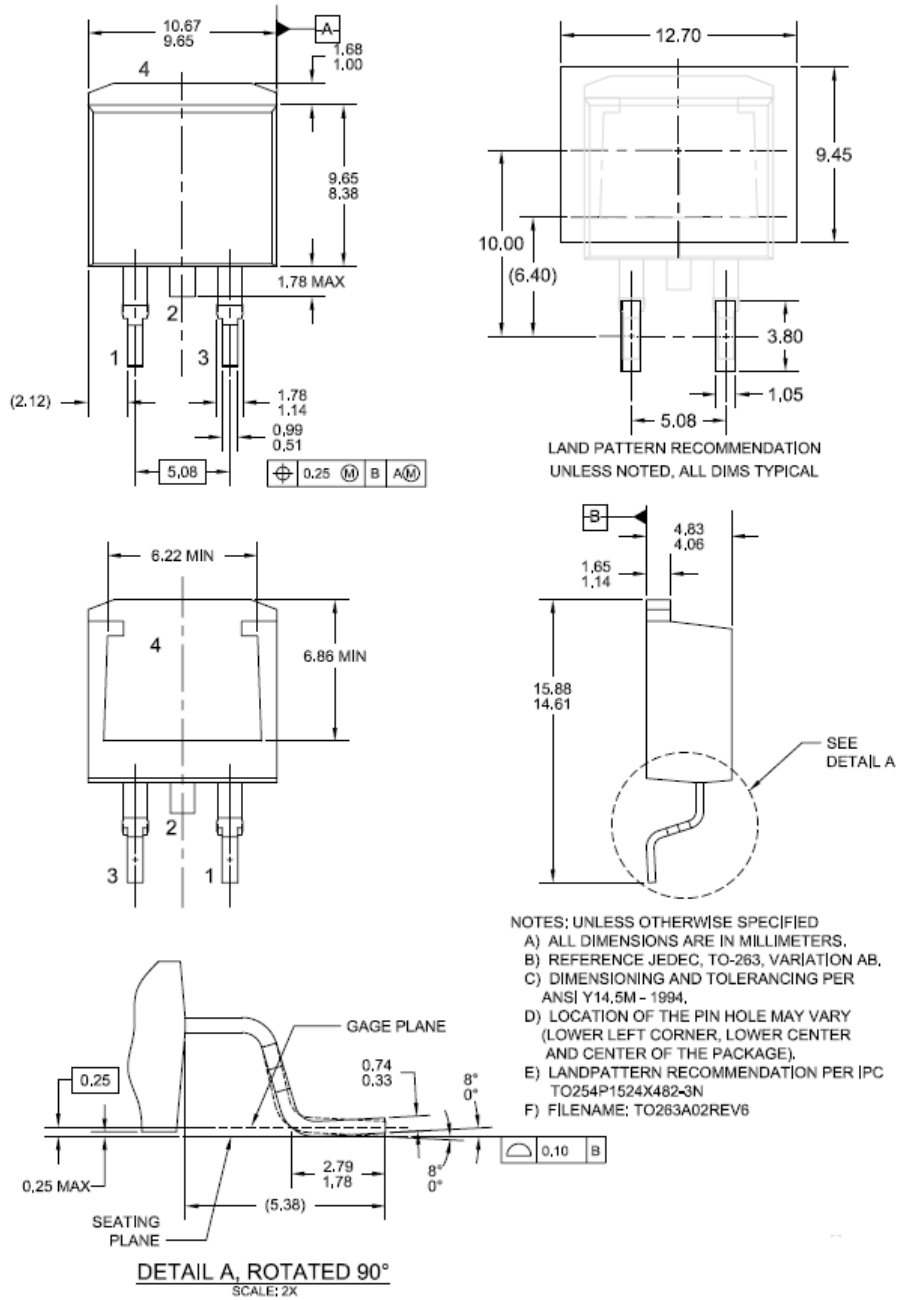


Figure 23. TO-263 2L (D2PAK) - 2LD, TO263, SURFACE MOUNT

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Dimensions in Millimeters



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